Diode Semiconductor Device - Page 1 of 1



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	aterial:
Glass	
Overall Leng	
	95 inches and 0.350 inches
Terminal Ler	ngth:
1.000 inches	
Overall Diam	neter:
Between 0.21	15 inches and 0.265 inches
Electrode Inf	ternally-electrically Connected To Case:
Cathode	
Mounting Me	ethod:
Terminal	
Features Pro	ovided:
Hermetically	sealed case
Semiconduc	tor Material:
Silicon	
Voltage Rati	ng In Volts Per Characteristic:
13.0 regulat	or voltage
Current Rati	ng Per Characteristic:
74.00 milliam	peres source cutoff current horsepower metric
Power Rating	g Per Characteristic:
1.0 watts sma	all-signal input power, common-collector preset
Maximum Op	perating Tempurature Per Measurement Point:
175.0 degree	s celsius ambient air
Test Data Do	ocument:
81349-mil-s-1	9500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; exclu	des commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmenta	al and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Typ	be And Quantity:
2 uninsulated	wire lead
Specification	n Data:
81349-mil-s-1	9500/115 government specification
Shelf Life:	
N/a	
Unit Of Meas	sure:
Demilitarizat	ion:
No	
Fiig:	
A110a0	